



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. 10/636,038
Filing Date August 6, 2003
Confirmation No. 9972
Inventor Gurtej S. Sandhu
Assignee Micron Technology, Inc.
Group Art Unit 1762
Examiner Eric B. Fuller
Attorney's Docket No. MI22-2194
Customer No. 021567
Title: Methods of Forming Material on a Substrate, and Method of Forming a
Field Effect Transistor Gate Oxide on a Substrate

RESPONSE TO MARCH 23, 2006 FINAL OFFICE ACTION
PRELIMINARY AMENDMENT TO ACCOMPANY RCE FILING

To: Mail Stop RCE
Commissioner for Patents
P. O. Box 1450
Alexandria, VA 22313-1450

VIA U.S. EXPRESS MAIL

From: Mark S. Matkin (Tel. 509-624-4276; Fax 509-838-3424)
Wells St. John P.S.
601 West First Avenue, Suite 1300
Spokane, WA 99201-3828

Responsive to the Final Office Action dated March 23, 2006, Applicant
amends and remarks as follows:

AMENDMENTS